

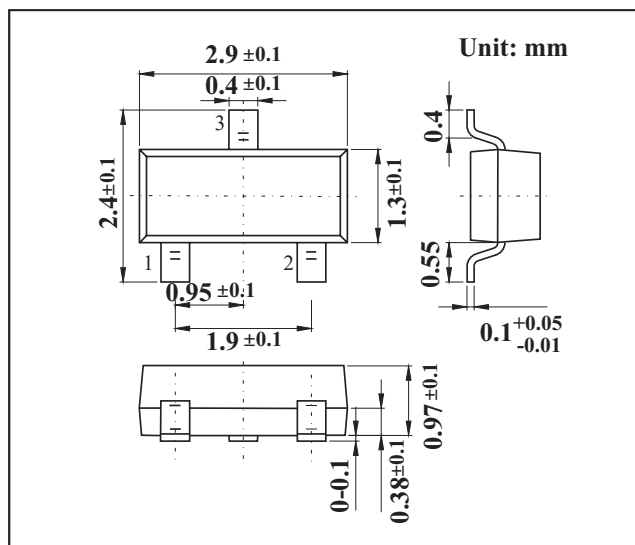
SOT-23 Small Signal Switching Diodes

FEATURES

- The plastic package carries Underwrites Laboratory Flammability Classification 94V-0
- Construction utilizes void-free molded plastic technique
- High reliability
- High temperature soldering guaranteed:260 °C/10 seconds at terminals
- Component in accordance to RoHs 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- Case style: SOT-23 molded plastic
- Mounting position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

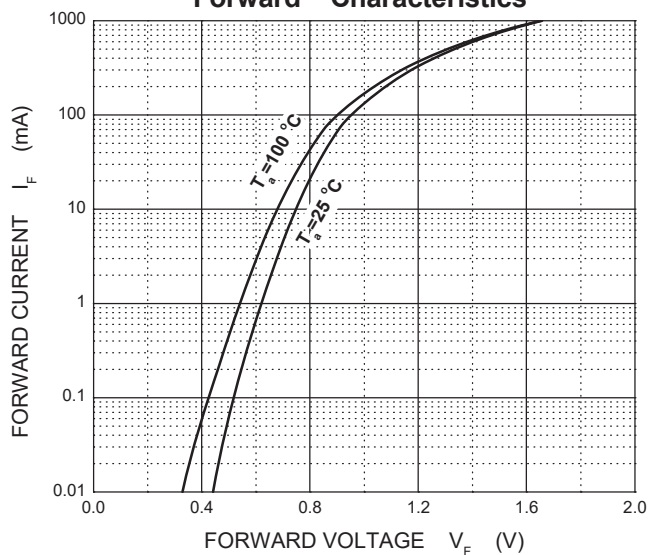
@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Limit	Unit
Repetitive peak reverse voltage	V_{RRM}	250	V
Working peak reverse voltage	V_{RWM}		
DC blocking voltage	V_R		
Forward continuous current	I_{FM}	400	mA
Average rectified output current	I_O	200	mA
Non-Repetitive Peak Forward Surge Current @t=8.3ms	I_{FSM}	2.5	A
Repetitive peak forward surge current	I_{FRM}	625	mA
Power dissipation	P_D	225	mW
Thermal resistance junction to ambient	$R_{\theta JA}$	555	°C/W
Junction temperature	T_J	150	°C
Storage temperature range	T_{STG}	-55~+150	°C

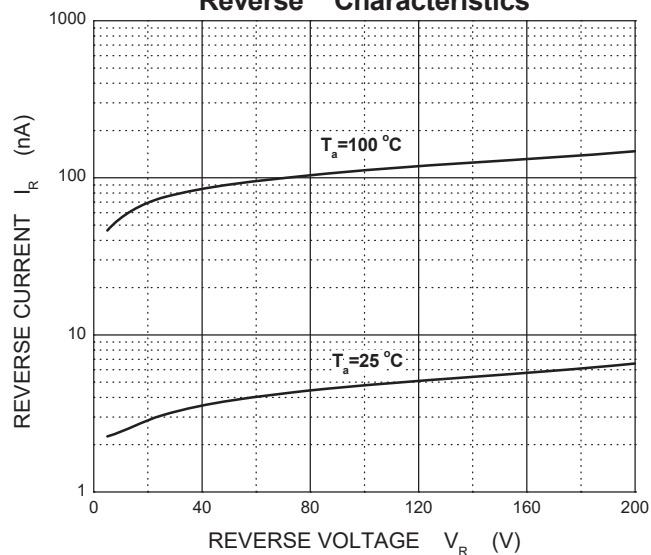
Parameter	Symbol	Test conditions	Min	Max	Unit
Reverse breakdown voltage	$V_{(BR)}$	$I_R=100\mu A$	250		V
Reverse voltage leakage current	I_R	$V_R=200V$		0.1	μA
Forward voltage	V_F	$I_F=100mA$ $I_F=200mA$		1000 1250	mV
Diode capacitance	C_D	$V_R=0V, f=1MHz$		5	pF
Reverse recovery time	t_{rr}	$I_F=I_R=30mA, I_{rr}=0.1 \times I_R, R_L=100\Omega$		50	ns

RATINGS AND CHARACTERISTIC CURVES

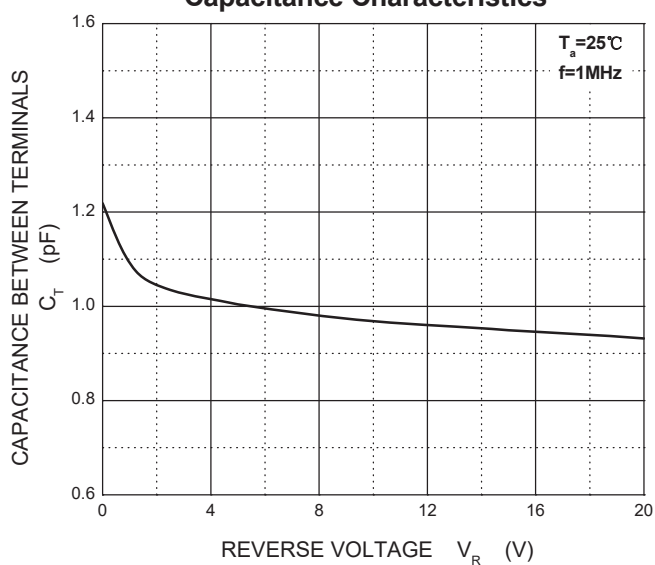
Forward Characteristics



Reverse Characteristics



Capacitance Characteristics



Power Derating Curve

